

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006-3 (SOT883) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Very fast switching
- ElectroStatic Discharge (ESD) protection: 2 kV HBM
- Leadless ultra small SMD plastic package: 1.0 × 0.6 × 0.48 mm

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

| Table 1. Quie | ck reference data | | | | | | |
|------------------------|----------------------------------|---|-----|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit |
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | - | 30 | V |
| V _{GS} | gate-source voltage | - | | -8 | - | 8 | V |
| I _D | drain current | V _{GS} = 4.5 V; T _{amb} = 25 °C | [1] | - | - | 0.9 | А |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 4.5 V; I _D = 0.9 A; T _j = 25 °C | | - | 390 | 470 | mΩ |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².





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5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------|---|--------------------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | G | gate | 1 | D |
| 2 | S | source | 2 🔲 🔡 3 | |
| 3 | D | drain | Transparent top view DFN1006-3 (SOT883) | G G S 017aaa255 |

6. Ordering information

| Table 3. Ordering information | | | | | | | |
|-----------------------------------|-----------|---|---------|--|--|--|--|
| Type number | Package | | | | | | |
| | Name | Description | Version | | | | |
| PMZ390UNE | DFN1006-3 | DFN1006-3: leadless ultra small plastic package; 3 solder lands | SOT883 | | | | |

7. Marking

| Table 4. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| PMZ390UNE | ZY |

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|-----|-----|------|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | 30 | V |
| V _{GS} | gate-source voltage | | | -8 | 8 | V |
| I _D | drain current | V_{GS} = 4.5 V; T_{amb} = 25 °C | [1] | - | 0.9 | А |
| | | V _{GS} = 4.5 V; T _{amb} = 100 °C | [1] | - | 0.6 | А |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$ | | - | 4 | А |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 350 | mW |
| | | | [1] | - | 715 | mW |
| | | T _{sp} = 25 °C | | - | 5430 | mW |
| Tj | junction temperature | | | -55 | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |
| Source-dra | in diode | , | 1 | 1 | | _ |
| I _S | source current | T _{amb} = 25 °C | [1] | - | 0.7 | А |

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

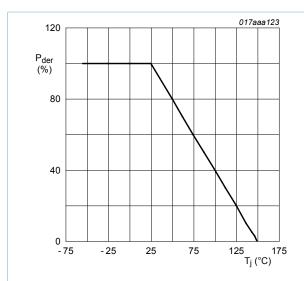
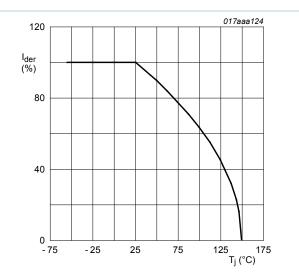


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



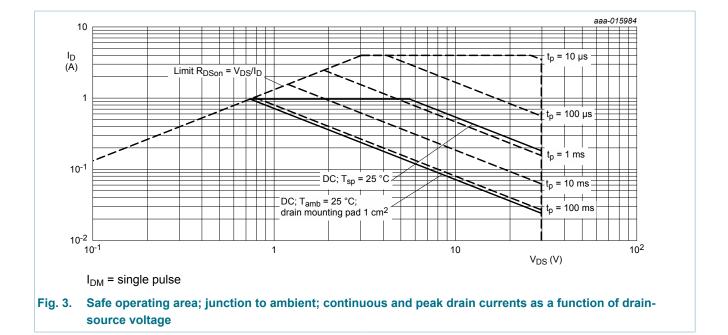


$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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9. Thermal characteristics

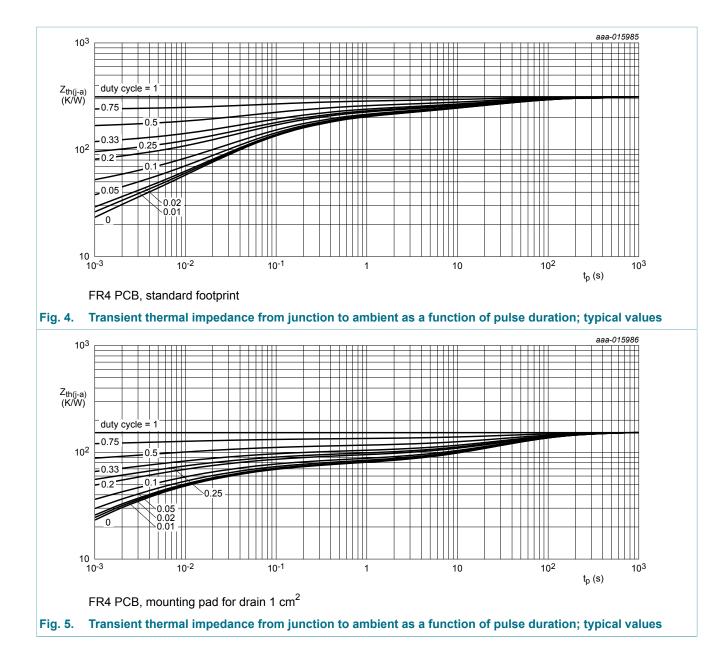
| Table 6. Thermal characteristics | | | | | | | | |
|----------------------------------|--|-------------|-----|-----|-----|-----|------|--|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
| ui(j-a) | thermal resistance | in free air | [1] | - | 315 | 360 | K/W | |
| | from junction to ambient | | [2] | - | 150 | 175 | K/W | |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | 20 | 23 | K/W | |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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10. Characteristics

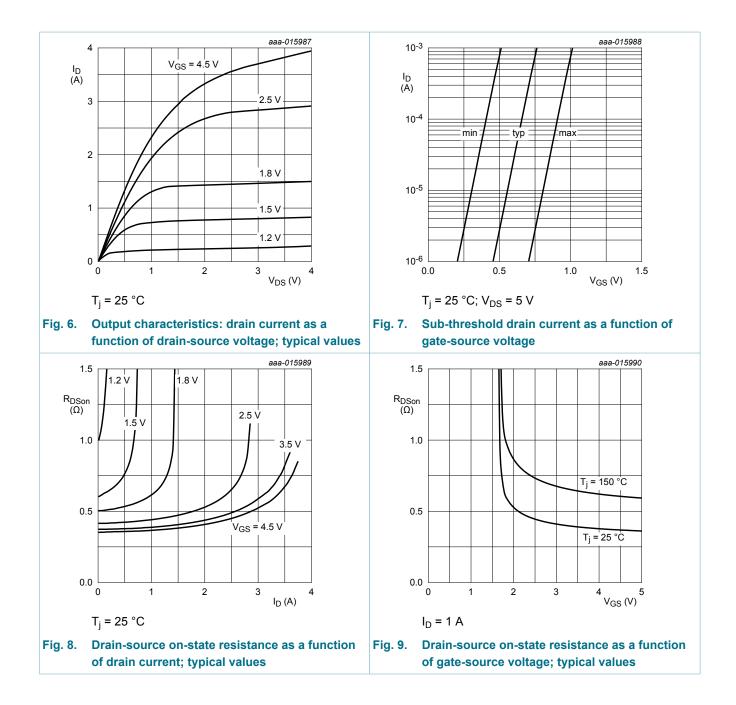
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|----------------------|-----------------------------------|---|------|------|------|------|
| Static chara | acteristics | · · · · | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C | 30 | - | - | V |
| V _{GSth} | gate-source threshold voltage | I _D = 250 μA; V _{DS} = V _{GS} ; T _j = 25 °C | 0.45 | 0.7 | 0.95 | V |
| I _{DSS} | drain leakage current | V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C | - | - | 1 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 5 | μA |
| | | V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -5 | μA |
| | | V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 1 | μA |
| | | V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -1 | μA |
| | | V_{GS} = 2.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 100 | nA |
| | | V_{GS} = -2.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -100 | nA |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 4.5 V; I _D = 0.9 A; T _j = 25 °C | - | 390 | 470 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 0.9 A; T _j = 150 °C | - | 660 | 790 | mΩ |
| | | V _{GS} = 2.5 V; I _D = 0.8 A; T _j = 25 °C | - | 460 | 620 | mΩ |
| | | V _{GS} = 1.8 V; I _D = 0.12 A; T _j = 25 °C | - | 530 | 770 | mΩ |
| | | V _{GS} = 1.5 V; I _D = 0.01 A; T _j = 25 °C | - | 610 | 1020 | mΩ |
| 9 _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 1 A; T _j = 25 °C | - | 2 | - | S |
| Dynamic ch | aracteristics | · · · · · | I | | | |
| Q _{G(tot)} | total gate charge | V_{DS} = 15 V; I _D = 0.8 A; V _{GS} = 4.5 V; | - | 0.8 | 1.3 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 0.1 | - | nC |
| Q _{GD} | gate-drain charge | - | - | 0.2 | - | nC |
| C _{iss} | input capacitance | V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V; | - | 41 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 6 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 5 | - | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 15 V; I _D = 0.8 A; V _{GS} = 4.5 V; | - | 4 | - | ns |
| t _r | rise time | R _{G(ext)} = 6 Ω; T _j = 25 °C | - | 8 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 12 | - | ns |
| t _f | fall time | | - | 3 | - | ns |
| Source-drai | in diode | · · · · · · · · · · · · · · · · · · · | I | | | |
| V _{SD} | source-drain voltage | I _S = 0.7 A; V _{GS} = 0 V; T _i = 25 °C | - | 0.86 | 1.2 | V |

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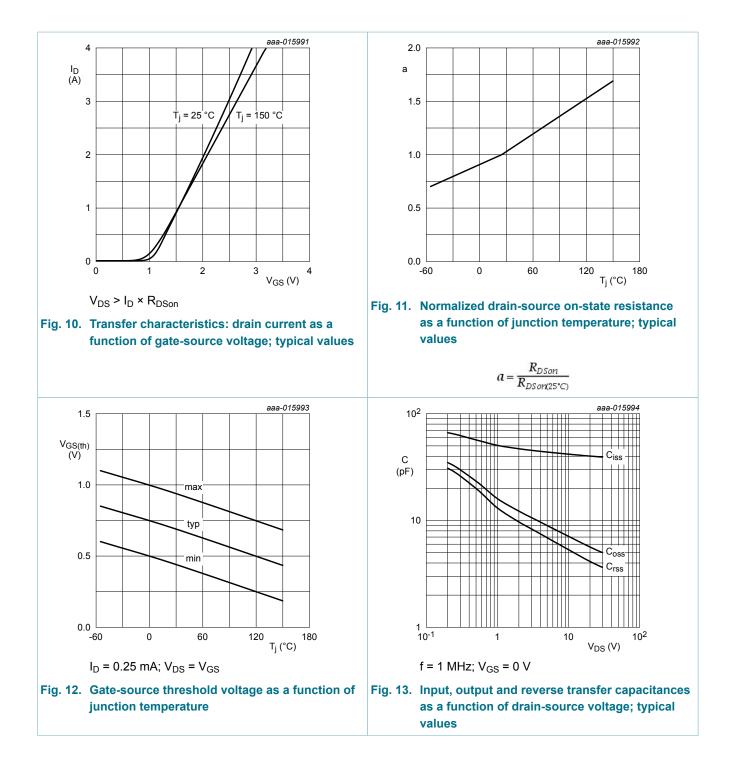
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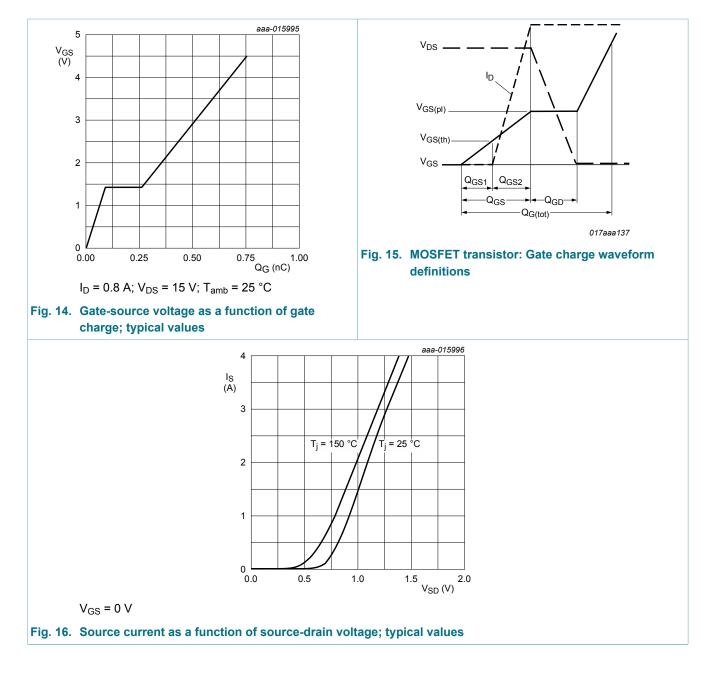
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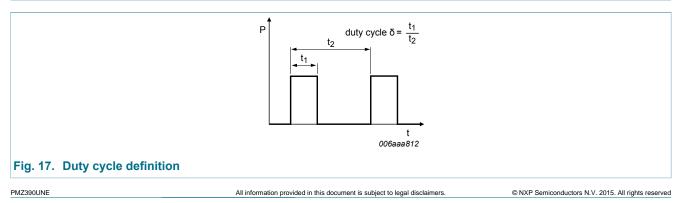


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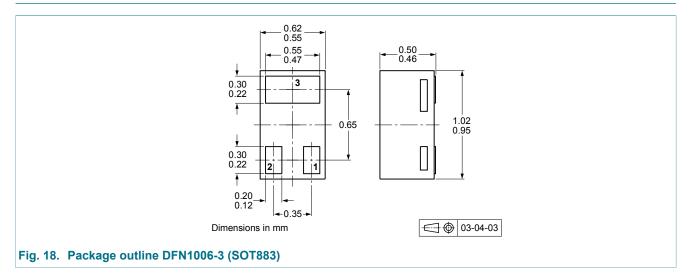


11. Test information

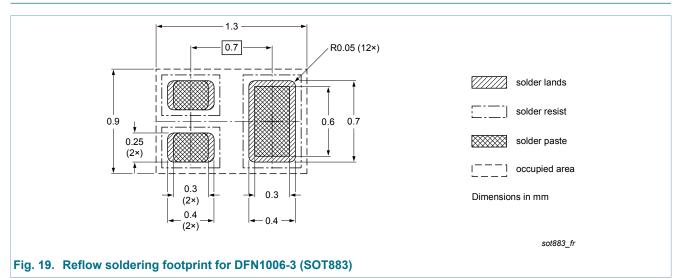


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12. Package outline



13. Soldering



14. Revision history

| Table 8. Revision his | story | | | |
|-----------------------|--------------|--------------------|---------------|------------|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
| PMZ390UNE v.1 | 20150312 | Product data sheet | - | - |

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15. Legal information

15.1 Data sheet status

| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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